NSN 5962-01-381-7808

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Used on: a05g0516-3 next assembly: a06g2795

Features Provided:

Programmed and ultraviolet erasable

Inclosure Configuration:

Dual-in-line

Case Outline Source And Designator:

D-10 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.6 volts applied and 6.25 volts applied

Time Rating Per Chacteristic:

200.00 nanoseconds af output megawatts

Memory Device Type:

Eprom

Hybrid Technology Type:

Monolithic

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0